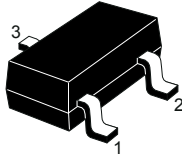
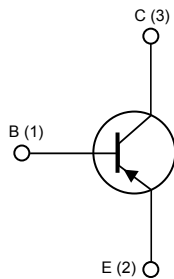


## Low voltage fast-switching PNP power transistor


**SOT-23**


PNPB1C3E2

### Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Miniature SOT-23 plastic package for surface mounting circuits

### Applications

- Led
- Battery charger
- Motor and relay driver
- Voltage regulation

### Description

The device is a PNP transistor manufactured using new “PB-HCD” (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

The complementary NPN is the 2STR1160.



#### Product status link

[2STR2160](#)

#### Product summary

<b>Order code</b>	2STR2160
<b>Marking</b>	2160
<b>Package</b>	SOT-23
<b>Packing</b>	Tape and reel

## 1 Electrical ratings

**Table 1. Absolute maximum rating**

Symbol	Parameter	Value	Unit
$V_{EBO}$	Emitter-base voltage ( $I_C = 0$ A)	-5	V
$V_{CBO}$	Collector-base voltage ( $I_E = 0$ A)	-60	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ A)	-60	V
$I_C$	Collector current	-1	A
$I_{CM}$	Collector peak current ( $t_p < 5$ ms)	-2	A
$P_{TOT}$	Total power dissipation at $T_A = 25$ °C	500	mW
$T_{stg}$	Storage temperature range	-65 to 150	°C
$T_J$	Maximum operating junction temperature	150	°C

**Table 2. Thermal data**

Symbol	Parameter	Value	Unit
$R_{thJA}^{(1)}$	Thermal resistance, junction-to-ambient	250	°C/W

1. Device mounted on a PCB area of 1 cm<sup>2</sup>.

## 2 Electrical characteristics

$T_C = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

**Table 3. Electrical characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{CBO}$	Collector cut-off current	$V_{CB} = -60\text{ V}$ , $I_E = 0\text{ A}$			-0.1	$\mu\text{A}$
$I_{EBO}$	Emitter cut-off current	$V_{EB} = -5\text{ V}$ , $I_C = 0\text{ A}$			-0.1	$\mu\text{A}$
$V_{(BR)CBO}$	Collector-base breakdown voltage	$I_C = -100\text{ }\mu\text{A}$ , $I_E = 0\text{ A}$	-60			V
$V_{(BR)CEO}^{(1)}$	Collector-emitter breakdown voltage	$I_B = 0\text{ A}$ , $I_C = -10\text{ mA}$	-60			V
$V_{(BR)EBO}$	Emitter-base breakdown voltage	$I_C = 0\text{ A}$ , $I_E = -100\text{ }\mu\text{A}$	-5			V
$V_{CE(sat)}$	Collector-emitter saturation voltage	$I_C = -0.5\text{ A}$ , $I_B = -50\text{ mA}$			260	mV
		$I_C = -1\text{ A}$ , $I_B = -100\text{ mA}$			480	
$V_{BE(sat)}$	Base-emitter saturation voltage	$I_C = -1\text{ A}$ , $I_B = -100\text{ mA}$			1.3	V
$h_{FE}$	DC current gain	$I_C = -0.5\text{ A}$ , $V_{CE} = -2\text{ V}$	180		560	
		$I_C = -1\text{ A}$ , $V_{CE} = -2\text{ V}$	45			
		$I_C = -2\text{ A}$ , $V_{CE} = -2\text{ V}$		30		
	Resistive load					
$t_{on}$	Turn-on time	$I_C = -1.5\text{ A}$ , $V_{CC} = -10\text{ V}$ ,		220		ns
$t_{off}$	Turn-off time	$I_{B1} = -I_{B2} = -150\text{ mA}$ , $V_{BB(off)} = 5\text{ V}$		500		ns

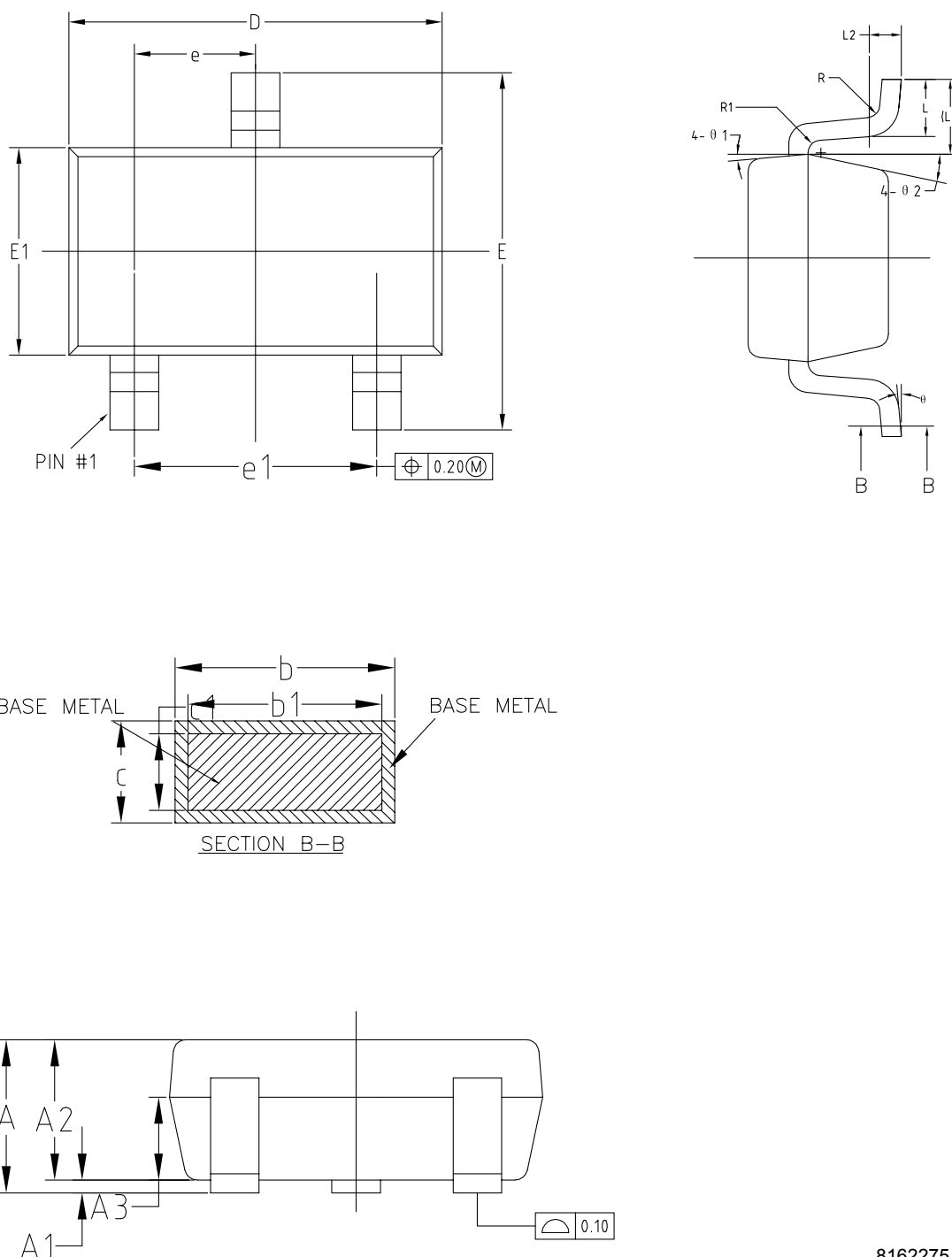
1. Pulsed: Pulse duration = 300  $\mu\text{s}$ , duty cycle  $\leq 2\%$ .

### 3 Package information

To meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

#### 3.1 SOT-23 package information

**Figure 1. SOT-23 package outline (dimensions are in mm)**

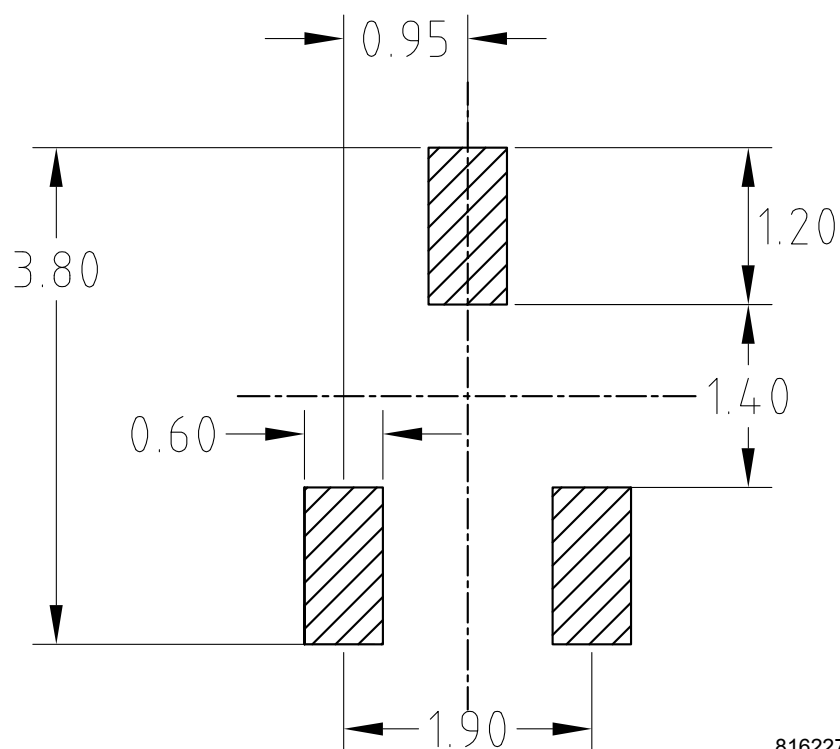


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**Table 4. SOT-23 package mechanical data**

Ref.	mm		
	Min.	Typ.	Max.
A			1.25
A1	0		0.15
A2	1	1.10	1.20
A3	0.60	0.65	0.70
b	0.36		0.50
b1	0.36	0.38	0.45
c	0.14		0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59 REF		
L2	0.25 BSC		
R	0.05		
R1	0.05		
θ	0°		8°
θ1	3°	5°	7°
θ2	6°		14°

**Figure 2. SOT-23 recommended footprint (dimensions in mm)**



8162275\_footprint\_REV3

## Revision history

**Table 5. Document revision history**

Date	Revision	Changes
18-Jun-2008	1	Initial release.
08-May-2014	2	Updated <i>Section 3: "Package mechanical data"</i> .
13-Mar-2015	3	Updated marking in <i>Table 1: "Device summary"</i>
21-Feb-2025	4	Updated <a href="#">Section 3.1: SOT-23 package information</a> . Minor text changes.

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